Silicon NPN Epitaxial VHF / UHF wide band amplifier

HITACHI

ADE-208-693 (Z) 1st. Edition Nov. 1998

Features

- Super compact package; $(1.4 \times 0.8 \times 0.59 \text{mm})$
- Capable low voltage operation ; $(V_{CE} = 1V)$

Outline

MEPAK



- 1. Emitter
- Base
- Collector

Note: Marking is "ZD-".

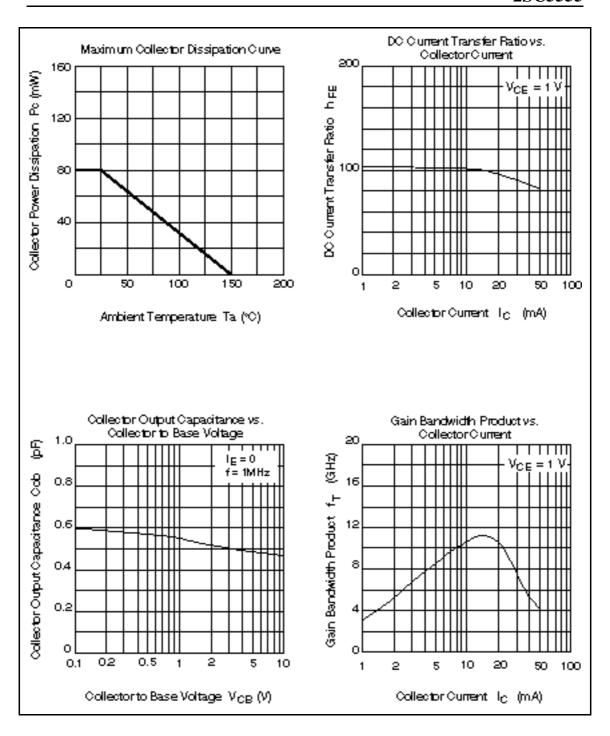


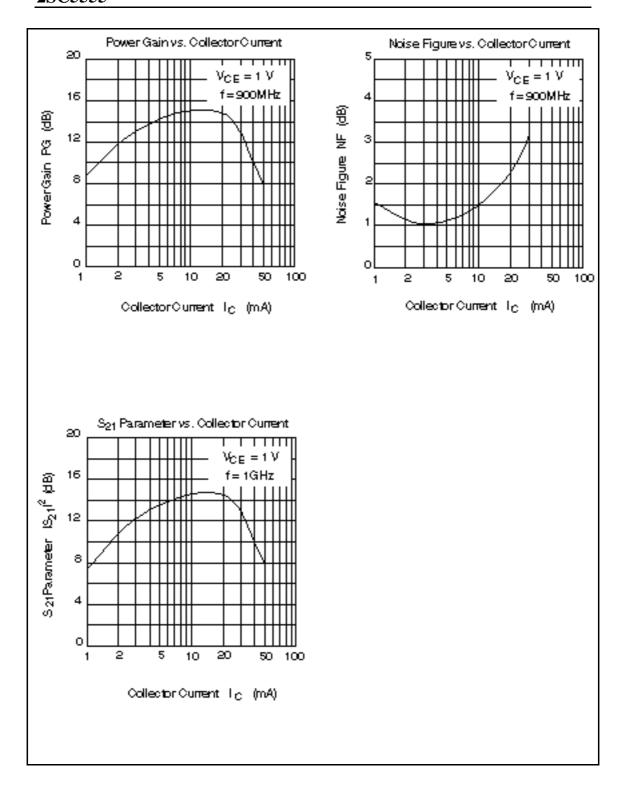
Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

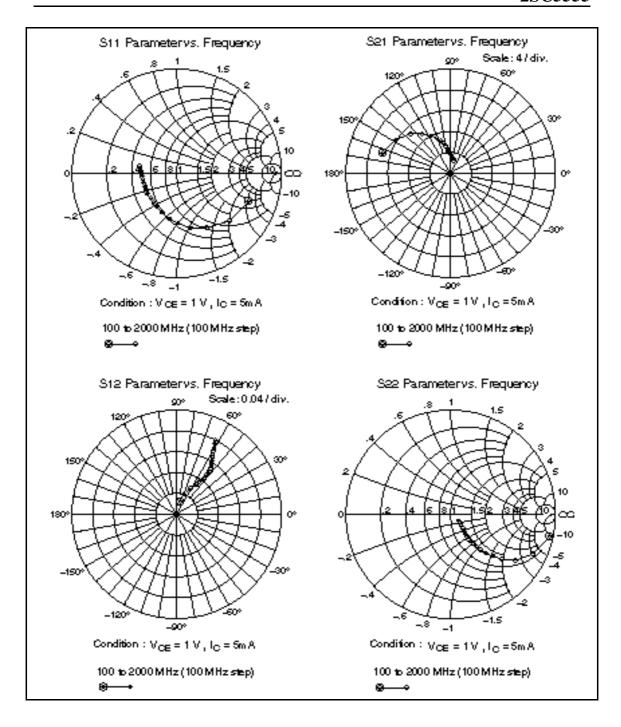
Item	Symbol	Ratings	Unit	
Collector to base voltage	V_{CBO}	15	V	
Collector to emitter voltage	V _{CEO}	8	V	
Emitter to base voltage	V_{EBO}	1.5	V	
Collector current	I _c	50	mA	
Collector power dissipation	Pc	80	mW	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	−55 to +150	°C	

Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	15	_	_	V	$I_{\text{C}} = 10 \mu A$, $I_{\text{E}} = 0$
Collector cutoff current	I _{CBO}	_	_	1	μΑ	$V_{CB} = 12V$, $I_E = 0$
Collector cutoff current	I _{CEO}	_	_	1	mA	$V_{CE} = 8V$, $R_{BE} =$
Emitter cutoff current	I _{EBO}	_	_	10	μΑ	$V_{EB} = 1.5V$, $I_{C} = 0$
DC current transfer ratio	h _{FE}	50	100	160	V	$V_{CE} = 1V$, $I_{C} = 5mA$
Collector output capacitance	Cob	_	0.55	0.85	pF	$V_{CB} = 1V$, $I_{E} = 0$ $f = 1MHz$
Gain bandwidth product	f⊤	6	9	_	GHz	$V_{CE} = 1V$, $I_{C} = 5mA$
Power gain	PG	11	14	_	dB	$V_{CE} = 1V, I_{C} = 5mA$ f = 900MHz
Noise figure	NF	_	1.1	2.0	dB	$V_{CE} = 1V, I_{C} = 5mA$ f = 900MHz





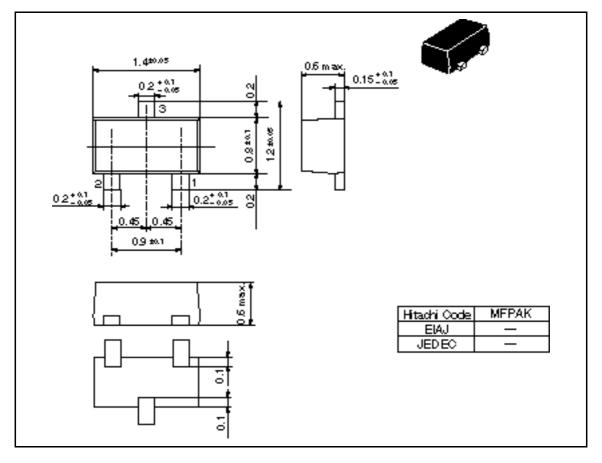


 $\textbf{Sparameter} \; (V_{CE} = 1V, \, I_{C} = 5mA, \, Zo = 50 \quad)$

	S11		S21		S12		S22	
f (MHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	0.734	-21.4	13.62	163.7	0.0220	78.7	0.956	-13.4
200	0.676	-41.9	12.34	148.7	0.0421	69.3	0.865	-25.5
300	0.598	-59.8	10.79	136.0	0.0572	61.9	0.753	-34.7
400	0.530	-75.6	9.38	126.5	0.0678	57.2	0.652	-41.0
500	0.471	-88.8	8.18	118.9	0.0756	55.0	0.568	-45.4
600	0.429	-100.8	7.19	112.9	0.0821	53.9	0.498	-48.3
700	0.395	-110.8	6.40	107.8	0.0881	53.4	0.442	-50.2
800	0.370	-120.6	5.74	103.5	0.0940	53.4	0.395	<i>–</i> 51.7
900	0.349	-130.0	5.20	100.1	0.0990	54.0	0.355	- 52.3
1000	0.336	-136.4	4.74	96.9	0.104	54.6	0.323	<i>–</i> 52.7
1100	0.332	-144.1	4.39	93.9	0.109	55.5	0.294	<i>–</i> 52.9
1200	0.327	-151.6	4.05	91.4	0.115	56.4	0.270	<i>–</i> 52.8
1300	0.322	-157.0	3.77	89.1	0.120	57.4	0.250	− 52.2
1400	0.325	-162.9	3.54	86.9	0.125	58.0	0.230	− 52.6
1500	0.322	-168.0	3.32	84.9	0.130	58.8	0.215	− 52.0
1600	0.331	-172.6	3.14	82.7	0.138	59.8	0.200	<i>–</i> 51.5
1700	0.338	-177.0	2.97	80.9	0.143	60.3	0.185	<i>–</i> 51.5
1800	0.337	179.0	2.84	79.4	0.149	61.5	0.171	<i>–</i> 51.2
1900	0.341	175.4	2.71	77.9	0.154	61.7	0.158	<i>–</i> 51.1
2000	0.358	170.8	2.59	76.0	0.161	62.4	0.147	-50.9

Package Dimensions

Unit: mm



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